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# GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER MODULE, 24 - 33 GHz OUTPUT

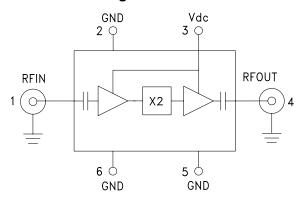


### Typical Applications

The HMC-C033 is suitable for:

- Clock Generation Applications: SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Military EW/Radar
- Space

### **Functional Diagram**



#### **Features**

High Output Power: +17 dBm

Low Input Power Drive: 0 to +6 dBm

100 KHz SSB Phase Noise: -132 dBc/Hz

Single Supply: +5V @ 81 mA Hermetically Sealed Module

Field Replaceable 2.92mm Connectors

-55 °C to +85 °C Operating Temperature

### **General Description**

The HMC-C033 is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a miniature hermetic module. When driven by a 3 dBm signal, the multiplier provides +17 dBm typical output power from 24 to 33 GHz. The Fo and 3Fo isolations are >20 dBc and >30 dBc respectively at 28 GHz with respect to output signal level. This frequency multiplier features DC blocked I/O's, and is ideal for use in LO multiplier chains for Pt to Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -132 dBc/Hz at 100 kHz offset helps maintain good system noise performance.

# Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +5V, 3 dBm Drive Level

Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input		12 - 16.5		GHz
Frequency Range, Output		24 - 33		
Output Power	14	17		dBm
Fo Isolation (with respect to output level)		20		dBc
3Fo Isolation (with respect to output level)		30		dBc
Input Return Loss		13		dB
Output Return Loss		20		dB
SSB Phase Noise (100 kHz Offset)		-132		dBc/Hz
Supply Current		81		mA

# **HMC-C033\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

# COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

# **DOCUMENTATION**

#### **Data Sheet**

• HMC-C033 Data Sheet

# REFERENCE MATERIALS •

#### **Technical Articles**

 Hittite Launches HMC-T2100 10 MHz to 20 GHz Synthesized Signal Generator

## DESIGN RESOURCES 🖳

- · HMC-C033 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

# **DISCUSSIONS**

View all HMC-C033 EngineerZone Discussions.

# SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

# TECHNICAL SUPPORT 🖳

Submit a technical question or find your regional support number.

# DOCUMENT FEEDBACK 🖳

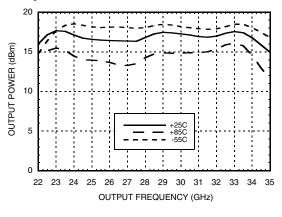
Submit feedback for this data sheet.



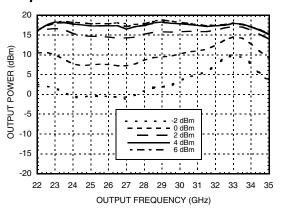


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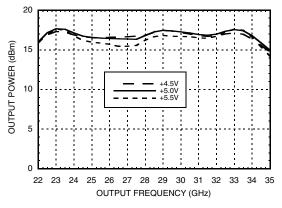
# Output Power vs. Temperature @ 3 dBm Drive Level



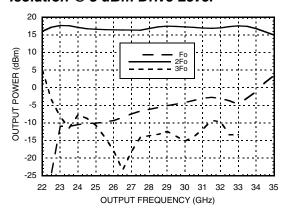
### **Output Power vs. Drive Level**



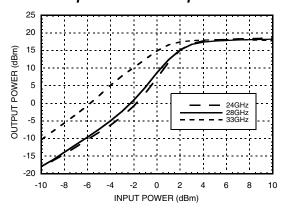
## Output Power vs. Supply Voltage @ 3 dBm Drive Level



### Isolation @ 3 dBm Drive Level



## **Output Power vs. Input Power**

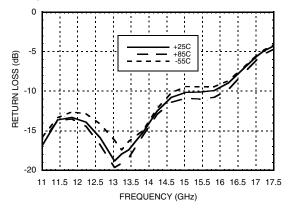




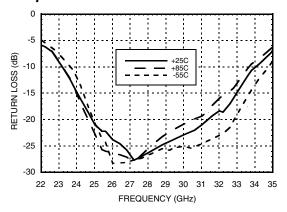


# GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER MODULE, 24 - 33 GHz OUTPUT

# Input Return Loss vs. Temperature @ 0 dBm Drive Level



## Output Return Loss vs. Temperature @ 0 dBm Drive Level



### **Absolute Maximum Ratings**

RF Input (Vdc = +5V)	+13 dBm	
Bias Supply Voltage (Vdc)	+6 Vdc	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	

### Typical Supply Current vs. Vdd

Vdd (Vdc)		ldd (mA)	
	4.5	81	
	5.0	81	
	5.5	81	

Note:

Multiplier will operate over full voltage range shown above.



### Pin Description

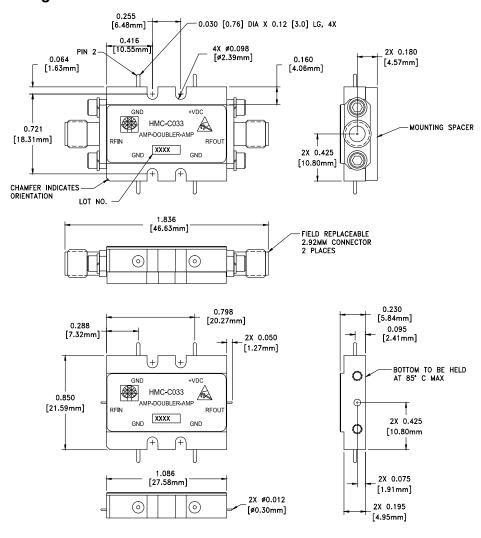
Pin Number	Function	Description	Interface Schematic
1	RFIN and RF Ground	Pin is AC coupled and matched to 50 Ohms. RFIN uses a female 2.92mm field replaceable connector.	RFINO— —
2, 5, 6	GND	One of these pins must be connected to power supply ground.	GND =
3	Vdc	Power supply voltage for the amplifier includes a 7.5V zener diode for over voltage and negative voltage protection	Vdc ○ 7.5V
4	RFOUT and RF Ground	Pin is AC coupled and matched to 50 Ohms. RFOUT uses a female 2.92mm field replaceable connector.	—   —○ RFOUT ——○





# GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER MODULE, 24 - 33 GHz OUTPUT

### **Outline Drawing**



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

## **Package Information**

Package Type	C-10	
Package Weight [1]	18.7 gms <sup>[2]</sup>	
Spacer Weight	3.3 gms <sup>[2]</sup>	

[1] Includes the connectors

[2] ±1 gms Tolerance

#### NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. TOLERANCES:
- $4.1 .XX = \pm 0.02$
- 4.2 .XXX = ±0.010
- 5. FIELD REPLACEABLE 2.92mm CONNECTORS TENSOLITE 231CCSF OR EQUIVALENT